

# LM715 **High Speed Operational Amplifier**

#### **General Description**

The LM715 is a high speed, high gain, monolithic operational amplifier intended for use in a wide range of applications where fast signal acquisition or wide bandwidth is required. The LM715 features fast settling time, high slew rate, low offsets, and high output swing for large signal applications. In addition, the device displays excellent temperature stability and will operate over a wide range of supply voltages.

**Features** 

- High slew rate— 100 V/µs (Inverting, A<sub>V</sub> = 1) typically
- Fast settling time— 800 ns typically
- Wide bandwidth— 65 MHz typically
- Wide operating supply range
- Wide input voltage ranges

## **Applications**

- Video amplifiers
- Active filters
- High speed data conversion



**Ordering Information** 

| Ordering information |                 |                        |  |  |  |  |  |
|----------------------|-----------------|------------------------|--|--|--|--|--|
| Device<br>Code       | Package<br>Code | Package<br>Description |  |  |  |  |  |
| LM715MH              | H10C            | Metal                  |  |  |  |  |  |
| LM715CH              | H10C            | Metal                  |  |  |  |  |  |
| LM715MJ              | J14A            | Ceramic DIP            |  |  |  |  |  |
| LM715CJ              | J14A            | Ceramic DIP            |  |  |  |  |  |

LM715 High Speed Operational Amplifier

October 1989

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| If Milita<br>please<br>Office/E   | ry/Aerospace<br>contact the<br>Distributors fo | specified d<br>National S<br>r availability | evices are requ<br>emiconductor S<br>and specification  | ired,<br>Sales<br>ns.                      | Inter<br>10<br>14 | nal Pow<br>L-Metal<br>L-Ceran | er Dissi<br>Can<br>nic DIP                     | ipation (    | Notes 1,      | 2)                 |                | 1.07W<br>1.36W |  |
|---|--|---|---|--|-------------------|-------------------------------|--|--------------|---------------|--------------------|----------------|----------------|--|
| Storage Temperature Range   |  |   | -65°C to +1   | -65°C to +175°C Sup                        |                   |                               |  | oply Voltage |               |                    |                |                |  |
| Operating Temperature Range<br>Extended (LM715M)<br>Commercial (LM715C) |  |   | −55°C to +1<br>0°C to +   | Dif<br>-55°C to +125°C Inp<br>0°C to +70°C |                   |                               | ierential Input Voltage<br>ut Voltage (Note 3) |              |               |                    |                | ±5V<br>±15V    |  |
| Lead Ter<br>Metal<br>(Solde   | mperature<br>Can and Ceran<br>ring, 60 sec.)   | nic DIP                                     | 3   | 00°C                                       |                   |                               |  |              |               |                    |                |                |  |
| LM71<br>Elect   | 5M and L<br>rical Cha                          | .M715C<br>racterist                         | <b>ics</b> T <sub>A</sub> = 25°C,   | V <sub>CC</sub> = ±                        | ±15V, ur          | nless oth                     | erwise   | specifie     | d             |                    |                |                |  |
| Symbol Barameter  |  | ameter                                      | Con   | Conditions                                 |                   | LM715M                        |  | LM715C       |               |                    | Units          |                |  |
| oyinibol  | i arameter                                     |   |   |  |                   | Min                           | Тур  | Max          | Min           | Тур                | Max            |                |  |
| V <sub>IO</sub>   | Input Offset V                                 | /oltage                                     | $R_S \le 10 \ k\Omega$  | 2  |                   |                               | 2.0  | 5.0          |               | 2.0                | 7.5            | mV             |  |
| I <sub>IO</sub>   | Input Offset C                                 | Current                                     |   |  |                   |                               | 70   | 250          |               | 70                 | 250            | nA             |  |
| I <sub>IB</sub>   | Input Bias Cu                                  | rrent                                       |   |  |                   |                               | 400  | 750          |               | 400                | 1500           | nA             |  |
| ZI  | Input Impeda                                   | nce   |   |  |                   |                               | 1.0  |              |               | 1.0                |                | MΩ             |  |
| R <sub>O</sub>  | Output Resist                                  | tance                                       |   |  |                   |                               | 75   |              |               | 75                 |                | Ω              |  |
| ICC   | Supply Curre                                   | nt  |   |  |                   |                               | 5.5  | 7.0          |               | 5.5                | 10             | mA             |  |
| Pc  | Power Consu                                    | mption                                      |   |  |                   |                               | 165  | 210          |               | 165                | 300            | mW             |  |
| VIR   | Input Voltage                                  | Range                                       |   |  |                   | ±10                           | ±12  |              | ±10           | ±12                | _              | V              |  |
| A <sub>VS</sub>   | Large Signal                                   | Voltage Gain                                | $R_L \ge 2.0 ks$  | $1, V_0 = 1$                               | ±10V              | 15                            | 30   |              | 10            | 30                 | _              | V/mV           |  |
| V   | Settling Time                                  |   | $V_0 = \pm 5.0$   | $V, A_V =$                                 | 1.0               |                               | 800  |              |               | 800                |                | ns             |  |
| IR  | I ransient<br>Response                         | Rise Lime                                   | $V_{\rm I} = 400 {\rm m}$   | $V, A_V =$                                 | 1.0               |                               | 30   | 60           |               | 30                 | 75             | ns             |  |
| <u>00</u>   | Claw Data                                      | Overshoot                                   | A = 100   |  |                   |                               | 25   | 40           |               | 25                 | 50             | %              |  |
| эн  | R Slew Rate                                    |   | $A_V = 100$   | $A_V = 100$                                |                   |                               | 70   |              |               | 20                 | -              | -              |  |
|   |  | $A_V = 10$                                  | $A_V = 10$<br>$A_V = 1.0$ (Non-Inverting)   |  |                   | 18                            |  | 10           | 18            |                    | - V/μs         |                |  |
|   |  |   | $A_V = 1.0$ (I  | nverting)                                  | ung)              | 10                            | 100  |              |               | 100                |                | -              |  |
| The follo   | wing specificat                                | ions apply ov                               | er the range of $-$   | 55°C ≤ T                                   | A ≤ +1            | 125°C fo                      | the LN   | //715M,      | and 0°C       | ≤ T <sub>A</sub> ≤ | ≤ +70°C        | for the        |  |
| Symbol Paramete   |  | neter                                       | Conditions  | LM715                                      |                   | 5M                            |  |              | LM715C        |                    |                | Unite          |  |
| oymbol  | Falameter                                      |   | Conditions  | Min  | Тур               | Max                           | I  | Min          | Тур           |                    | Max            | 01113          |  |
| V <sub>IO</sub>   | Input Offset                                   | Voltage                                     | $R_S \le 10 \ k\Omega$  |  |                   | 7.5                           |  |              |               |                    | 10             | mV             |  |
| IIO   | Input Offset                                   | Current                                     | $T_A = T_{A Max}$   |  |                   | 250                           |  |              |               |                    | 250            | nA             |  |
|   |  |   | $T_A = T_{A Min}$   |  |                   | 800                           |  |              |               |                    | 750            |                |  |
| I <sub>IB</sub>   | Input Bias C                                   | urrent                                      | $T_A = T_{A Max}$   |  |                   | 0.75                          |  |              |               | _                  | 1.5            | μΑ             |  |
| CMR   | Common Me<br>Rejection                         | ode   | $\frac{\Gamma_{A} - \Gamma_{A \text{ Min}}}{R_{S} \le 10 \text{ k}\Omega}$                                  | 74   | 92                | 4.0                           | (N   | 74<br>ote 4) | 92<br>(Note 4 | 1)                 | 7.5            | dB             |  |
| PSRR  | Power Supp<br>Rejection R                      | ly<br>atio                                  | $R_{S} \leq 10 \ k\Omega$   |  | 45                | 300                           |  |              | 45<br>(Note 4 | 4) (1              | 400<br>Note 4) | μV/V           |  |
| A <sub>VS</sub>   | Large Signa<br>Voltage Gai                     | n   | $\label{eq:relation} \overline{ \begin{matrix} R_L \geq 2.0 \ k\Omega, \\ V_O = \ \pm \ 10V \end{matrix} }$ | 10   |                   |                               |  | 8            |               |                    |                | V/mV           |  |
|   | Output Valte                                   | an Culina                                   | D 0010  | 1  | 1                 |                               |  |              | 1 10          | 1                  |                | V .            |  |

Note 2: Ratings apply to ambient temperature at 25°C. Above this temperature, derate the 10L-Metal Can at 7.1 mV Note 3: For supply voltages less than  $\pm$ 15V, the absolute maximum input voltage is equal to the supply voltage. Note 4:  $T_A = 25^{\circ}C$  only. υ,





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### **Applications Information**

Non-Inverting Compensation Components Values

| •                   |        |         |         |  |  |  |
|---------------------|--------|---------|---------|--|--|--|
| Closed Loop<br>Gain | C1     | C2      | C3      |  |  |  |
| 1000                | 10 pF  |         |         |  |  |  |
| 100                 | 50 pF  |         | 250 pF  |  |  |  |
| 10 (Note)           | 100 pF | 500 pF  | 1000 pF |  |  |  |
| 1                   | 500 pF | 2000 pF | 1000 pF |  |  |  |

Note: For gain 10, compensation may be simplified by removing C2, C3 and adding a 200 pF capacitor (C4) between Lead 7 and 10.

Frequency Compensation Circuit



Suggested Values of Compensation Capacitors vs Closed Loop Voltage Gain



# Layout Instructions

Layout—The layout should be such that stray capacitance is minimal.

Supplies—The supplies should be adequately bypassed. Used of 0.1  $\mu\text{F}$  high quality ceramic capacitors is recommended.

Note: All lead numbers on this page apply to metal package.

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**Ringing**—Excessive ringing (long acquisition time) may occur with large capacitive loads. This may be reduced by isolating the capacitive load with a resistance of  $100\Omega$ . Large source resistances may also give rise to the same problem and this may be decreased by the addition of a capacitance across the feedback resistance. A value of around 50 pF for unity gain configuration and around 3.0 pF for gain 10 should be adequate.

Latch Up—This may occur when the amplifier is used as a voltage follower. The inclusion of a diode between leads 6 and 2 with the cathode toward lead 2 is the recommended preventive measure.

#### **Typical Applications**



**High Speed Integrator** 





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